

UTT60N06

Power MOSFET

N-CHANNEL ENHANCEMENT
MODE POWER MOSFET

■ DESCRIPTION

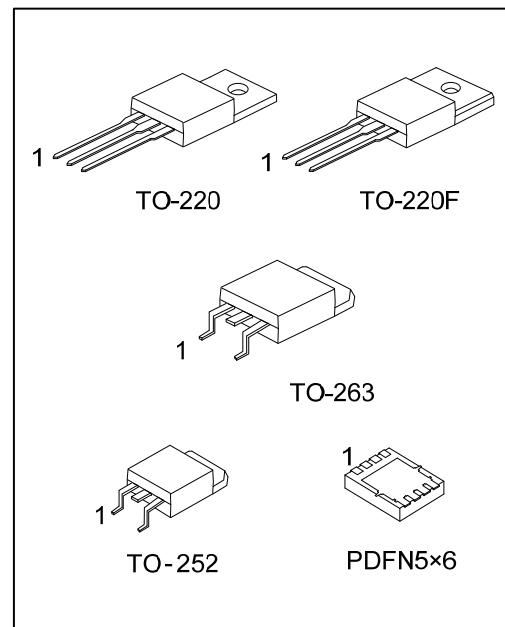
The UTC **UTT60N06** is n-channel enhancement mode power field effect transistors with stable off-state characteristics, fast switching speed and low thermal resistance. usually used at telecom and computer applications.

■ FEATURES

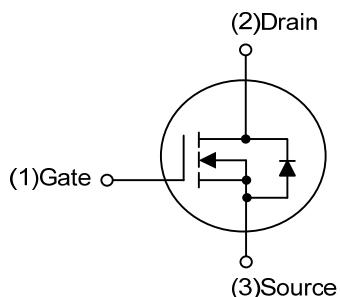
* $R_{DS(ON)} \leq 18 \text{ m}\Omega$ @ $V_{GS}=10\text{V}$, $I_D=30\text{A}$

* Fast switching capability

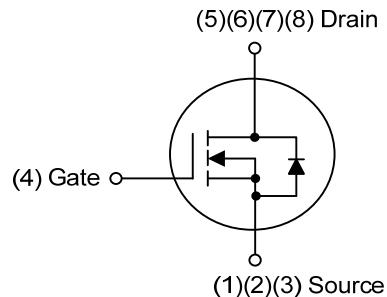
* Avalanche energy Specified



■ SYMBOL



TO-220/TO-220F/TO-252/TO-263



PDFN5x6

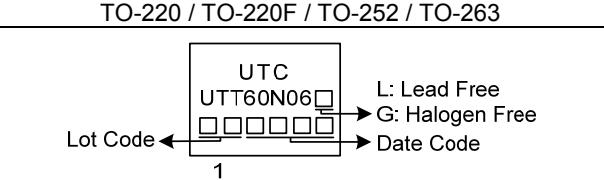
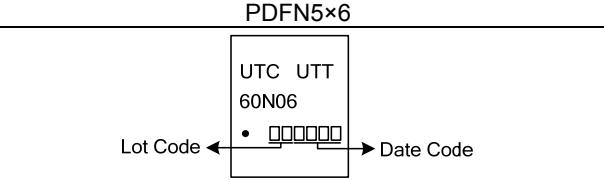
■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment								Packing
Lead Free	Halogen Free		1	2	3	4	5	6	7	8	
UTT60N06L-TA3-T	UTT60N06G-TA3-T	TO-220	G	D	S	-	-	-	-	-	Tube
UTT60N06L-TF3-T	UTT60N06G-TF3-T	TO-220F	G	D	S	-	-	-	-	-	Tube
UTT60N06L-TN3-R	UTT60N06G-TN3-R	TO-252	G	D	S	-	-	-	-	-	Tape Reel
UTT60N06L-TQ2-T	UTT60N06G-TQ2-T	TO-263	G	D	S	-	-	-	-	-	Tube
UTT60N06L-TQ2-R	UTT60N06G-TQ2-R	TO-263	G	D	S	-	-	-	-	-	Tape Reel
UTT60N06L-P5060-R	UTT60N06G-P5060-R	PDFN5x6	S	S	S	G	D	D	D	D	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

 (1)Packing Type	(1) T: Tube, R: Tape Reel
 (2)Package Type	(2) TA3: TO-220, TF3: TO-220F, TN3: TO-252, TQ2: TO-263, P5060: PDFN5x6
 (3)Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free

■ MARKING

TO-220 / TO-220F / TO-252 / TO-263	PDFN5×6
 <p>L: Lead Free G: Halogen Free</p>	

■ ABSOLUTE MAXIMUM RATINGS ($T_C = 25^\circ\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain to Source Voltage		V_{DSS}	60	V
Gate to Source Voltage		V_{GS}	± 20	V
Continuous Drain Current	$T_C = 25^\circ\text{C}$	I_D	60	A
	$T_C = 100^\circ\text{C}$		39	A
Drain Current Pulsed (Note 2)		I_{DM}	120	A
Avalanche Energy	Single Pulsed	E_{AS}	100	mJ
Power Dissipation ($T_C=25^\circ\text{C}$)	TO-220/TO-263	P_D	100	W
	TO-220F		70.62	W
	TO-252		70	W
	PDFN5×6		88	W
Junction Temperature		T_J	+150	$^\circ\text{C}$
Storage Temperature		T_{STG}	-55 ~ +150	$^\circ\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repeatability rating: pulse width limited by junction temperature.

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	TO-220/TO-220F	θ_{JA}	62.5	$^\circ\text{C}/\text{W}$
	TO-263		110	$^\circ\text{C}/\text{W}$
	TO-252		40.3 (Note)	$^\circ\text{C}/\text{W}$
	PDFN5×6			
Junction to Case	TO-220/TO-263	θ_{JC}	1.25	$^\circ\text{C}/\text{W}$
	TO-220F		1.77	$^\circ\text{C}/\text{W}$
	TO-252		1.8	$^\circ\text{C}/\text{W}$
	PDFN5×6		1.4 (Note)	$^\circ\text{C}/\text{W}$

Note: The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.

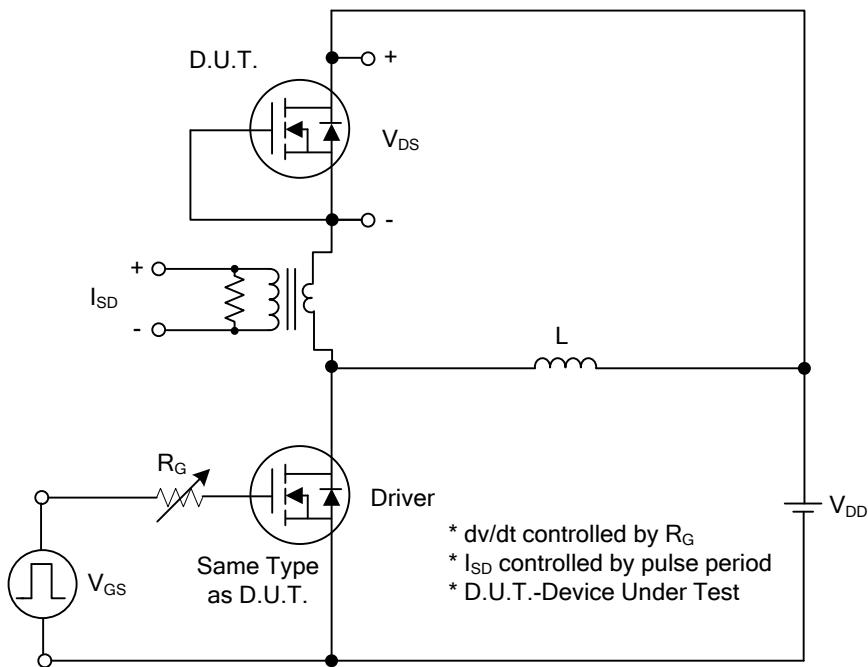
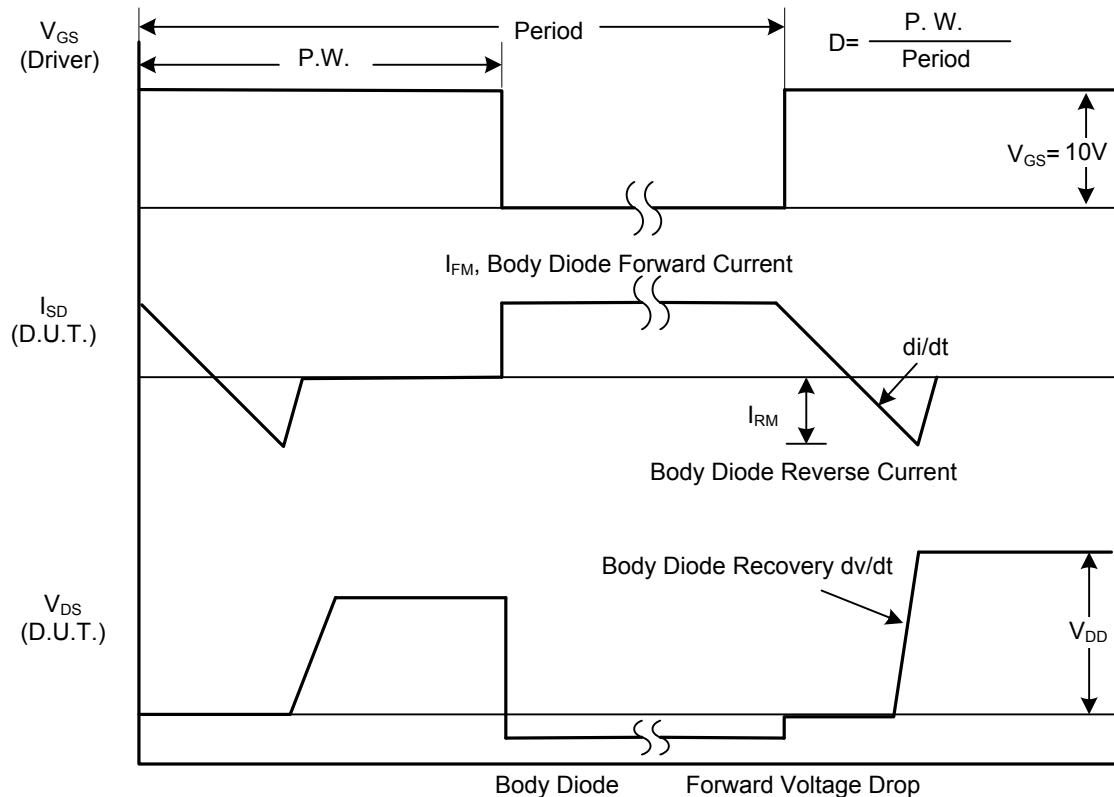
■ ELECTRICAL CHARACTERISTICS ($T_c = 25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=250\mu\text{A}$	60			V
Drain-Source Leakage Current	I_{DSS}	$V_{\text{DS}}=60\text{V}, V_{\text{GS}}=0\text{V}$		1		μA
Gate-Source Leakage Current	Forward	$V_{\text{GS}}=20\text{V}, V_{\text{DS}}=0\text{V}$		100		nA
	Reverse	$V_{\text{GS}}=-20\text{V}, V_{\text{DS}}=0\text{V}$		-100		nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{\text{GS}(\text{TH})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$	2.0		4.0	V
Static Drain-Source On-State Resistance	$R_{\text{DS}(\text{ON})}$	$V_{\text{GS}}=10\text{V}, I_{\text{D}}=30\text{A}$		14	18	$\text{m}\Omega$
DYNAMIC CHARACTERISTICS						
Input Capacitance	C_{ISS}	$V_{\text{GS}}=0\text{V}, V_{\text{DS}}=25\text{V}, f=1\text{MHz}$		2000		pF
Output Capacitance	C_{OSS}			400		pF
Reverse Transfer Capacitance	C_{RSS}			115		pF
SWITCHING CHARACTERISTICS						
Total Gate Charge	Q_G	$V_{\text{DS}}=30\text{V}, V_{\text{GS}}=10\text{V}, I_{\text{D}}=60\text{A}$ (Note 1,2)		39	60	nC
Gate-Source Charge	Q_{GS}			12		nC
Gate-Drain Charge (Miller Charge)	Q_{GD}			10		nC
Turn-On Delay Time	$t_{\text{D(ON)}}$	$V_{\text{DD}}=48\text{V}, V_{\text{GS}}=10\text{V}, I_{\text{D}}=60\text{A}$ (Note 1, 2)		12	30	ns
Rise Time	t_R			11	30	ns
Turn-Off Delay Time	$t_{\text{D(OFF)}}$			25	50	ns
Fall Time	t_F			15	30	ns
SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS						
Continuous Source Current	I_S				60	A
Pulsed Source Current	I_{SM}				120	
Diode Forward Voltage	V_{SD}	$V_{\text{GS}}=0\text{V}, I_{\text{S}}=60\text{A}$			1.6	V
Reverse Recovery Time	t_{rr}	$I_{\text{S}}=60\text{A}, V_{\text{GS}}=0\text{V},$		60		ns
Reverse Recovery Charge	Q_{rr}	$dI_{\text{F}}/dt=100\text{A}/\mu\text{s}$ (Note 1)		3.4		μC

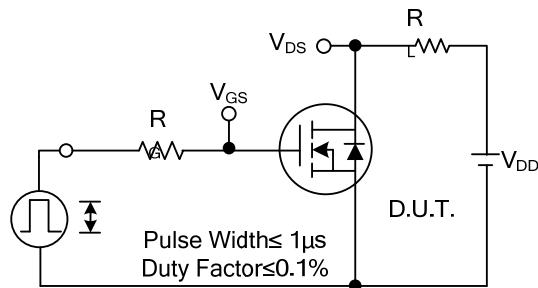
Notes: 1. Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$.

2. Essentially independent of operating temperature.

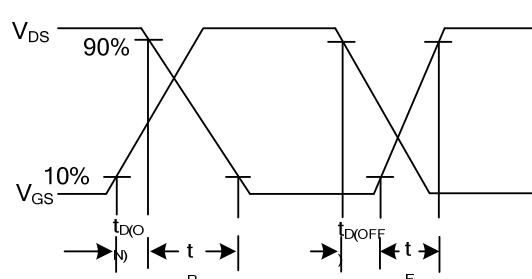
■ TEST CIRCUITS AND WAVEFORMS

Peak Diode Recovery dv/dt Test CircuitPeak Diode Recovery dv/dt Waveforms

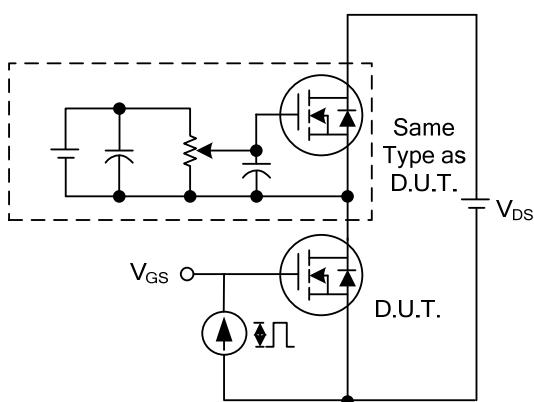
■ TEST CIRCUITS AND WAVEFORMS



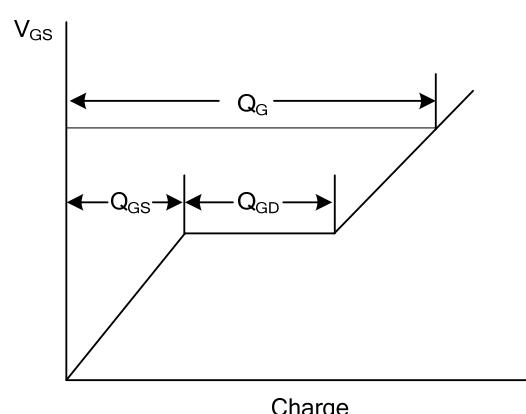
Switching Test Circuit



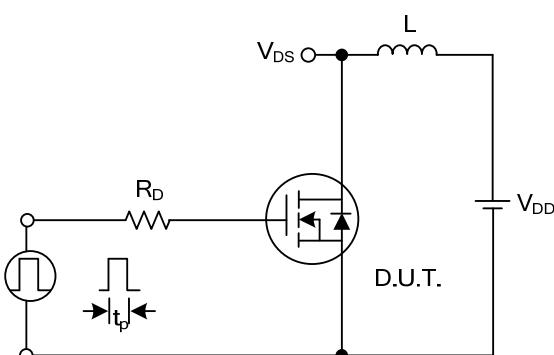
Switching Waveforms



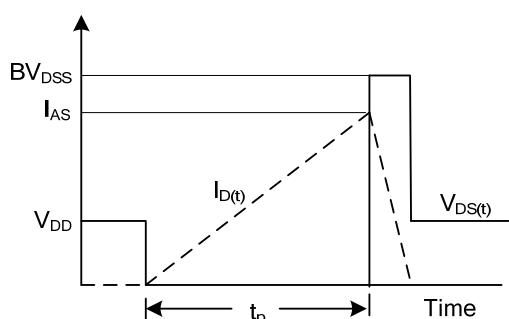
Gate Charge Test Circuit



Gate Charge Waveform

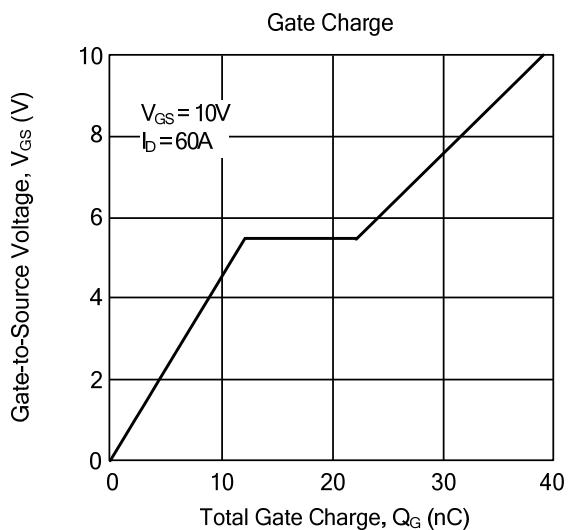
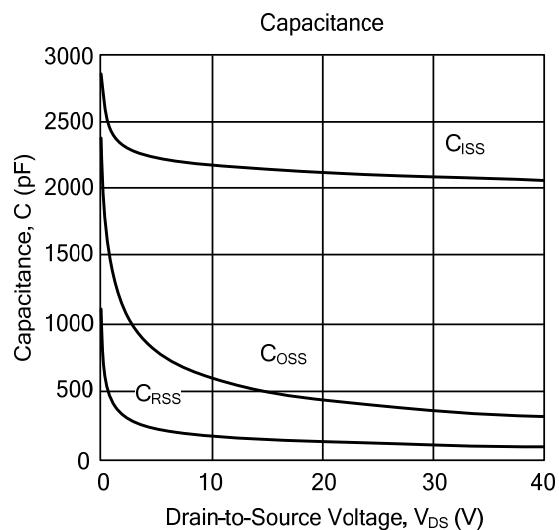
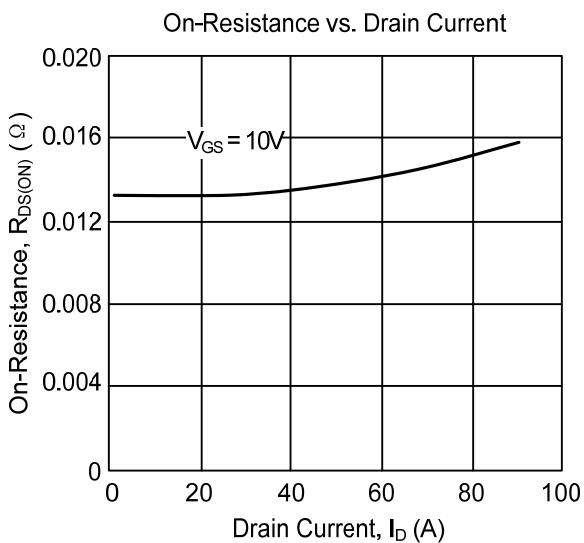
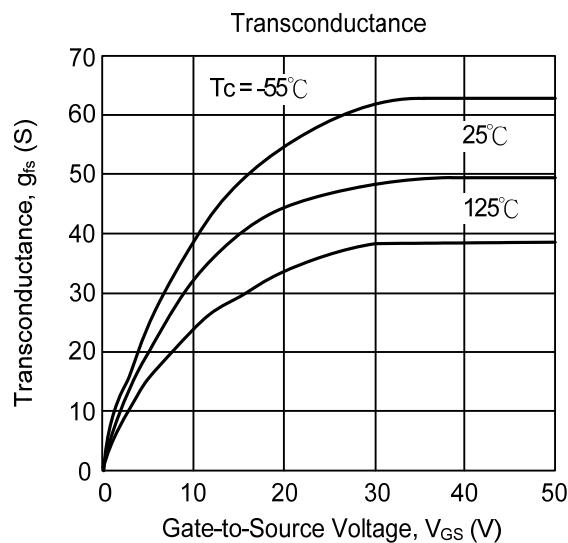
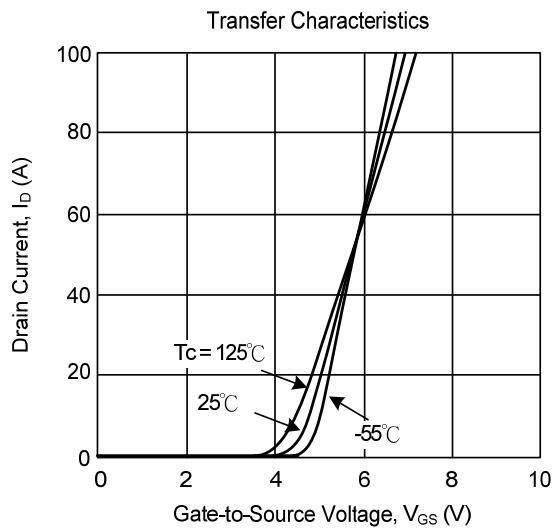
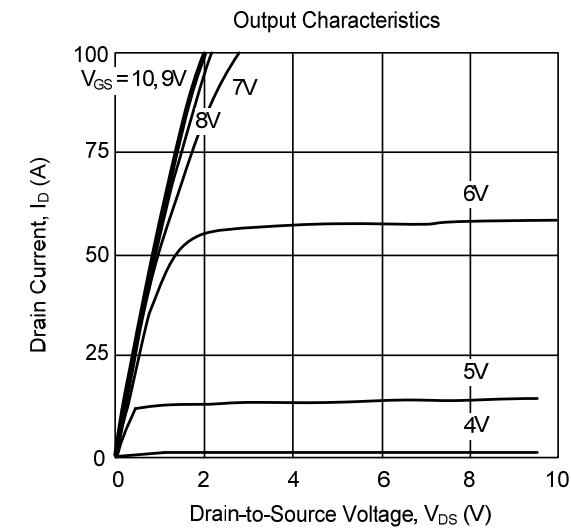


Unclamped Inductive Switching Test Circuit

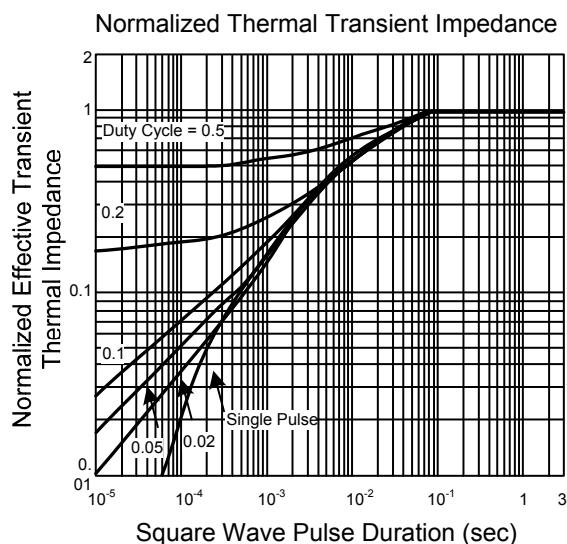
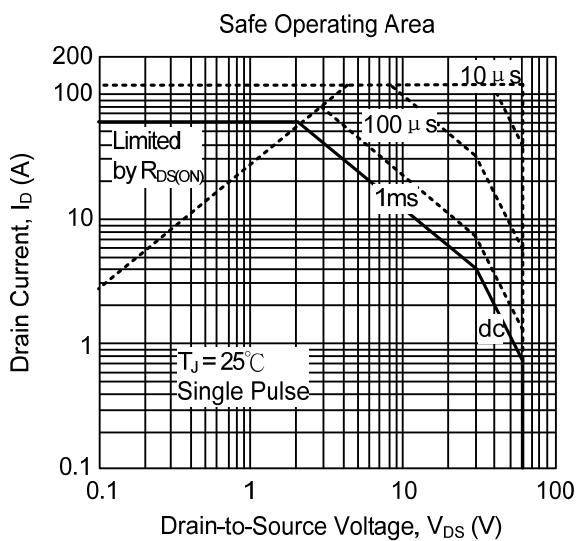
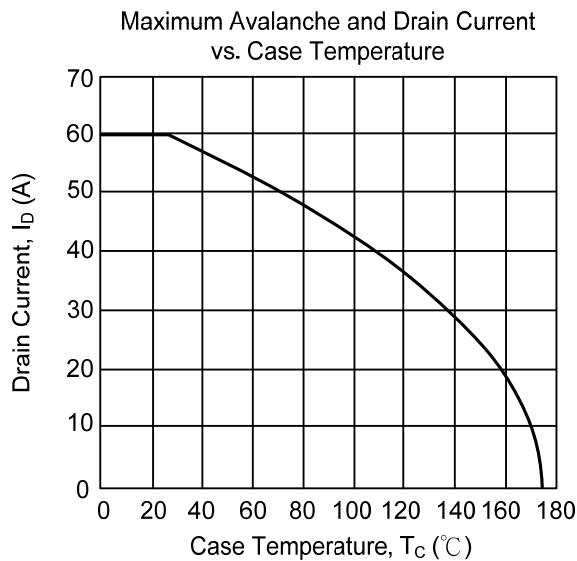
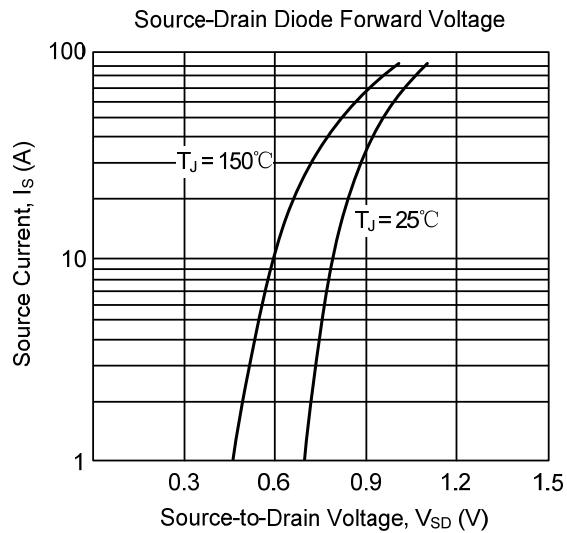
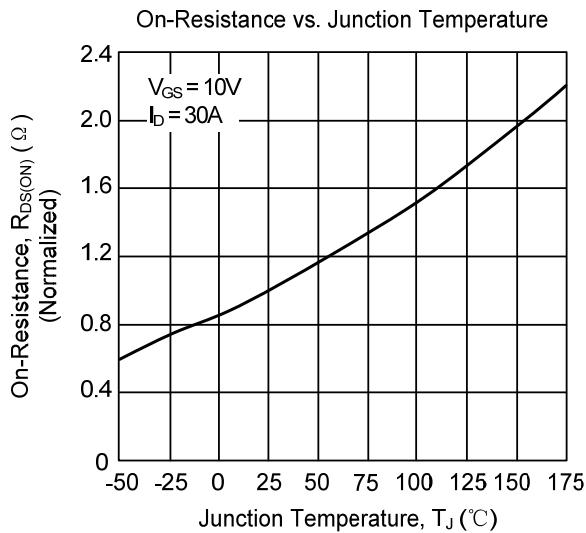


Unclamped Inductive Switching Waveforms

■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS (Cont.)



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